

### FEATURES

**Ultralow offset voltage**

$T_A = 25^\circ\text{C}$ ,  $25 \mu\text{V}$  maximum

**Outstanding offset voltage drift**  $0.1 \mu\text{V}/^\circ\text{C}$  maximum

**Excellent open-loop gain and gain linearity**

12 V/ $\mu\text{V}$  typical

**CMRR:** 130 dB minimum

**PSRR:** 115 dB minimum

**Low supply current** 2.0 mA maximum

**Fits industry-standard precision op amp sockets**

### GENERAL DESCRIPTION

The OP177 features one of the highest precision performance of any op amp currently available. Offset voltage of the OP177 is only  $25 \mu\text{V}$  maximum at room temperature. The ultralow  $V_{OS}$  of the OP177 combines with its exceptional offset voltage drift ( $TCV_{OS}$ ) of  $0.1 \mu\text{V}/^\circ\text{C}$  maximum to eliminate the need for external  $V_{OS}$  adjustment and increases system accuracy over temperature.

The OP177 open-loop gain of  $12 \text{ V}/\mu\text{V}$  is maintained over the full  $\pm 10 \text{ V}$  output range. CMRR of 130 dB minimum, PSRR of 120 dB minimum, and maximum supply current of 2 mA are just a few examples of the excellent performance of this

### PIN CONFIGURATION

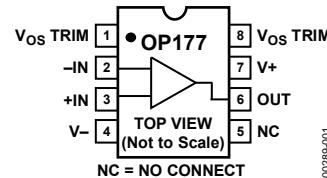


Figure 1. 8-Lead PDIP (P-Suffix),  
8-Lead SOIC (S-Suffix)

operational amplifier. The combination of outstanding specifications of the OP177 ensures accurate performance in high closed-loop gain applications.

This low noise, bipolar input op amp is also a cost effective alternative to chopper-stabilized amplifiers. The OP177 provides chopper-type performance without the usual problems of high noise, low frequency chopper spikes, large physical size, limited common-mode input voltage range, and bulky external storage capacitors.

The OP177 is offered in the  $-40^\circ\text{C}$  to  $+85^\circ\text{C}$  extended industrial temperature ranges. This product is available in 8-lead PDIP, as well as the space saving 8-lead SOIC.

### FUNCTIONAL BLOCK DIAGRAM

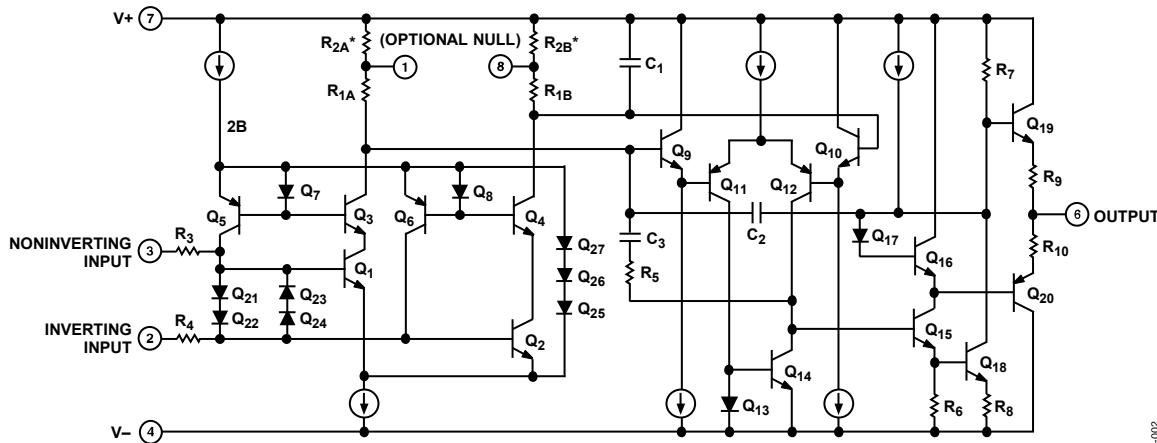


Figure 2. Simplified Schematic

Rev. F

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One Technology Way, P.O. Box 9106, Norwood, MA 02062-9106, U.S.A.  
Tel: 781.329.4700 [www.analog.com](http://www.analog.com)  
Fax: 781.461.3113 ©1995–2009 Analog Devices, Inc. All rights reserved.

## TABLE OF CONTENTS

Features .....	1
Pin Configuration.....	1
General Description .....	1
Functional Block Diagram .....	1
Revision History .....	2
Specifications.....	3
Electrical Characteristics.....	3
Test Circuits.....	4
Absolute Maximum Ratings.....	5
Thermal Resistance .....	5
ESD Caution.....	5
Typical Performance Characteristics .....	6

## REVISION HISTORY

### 3/09—Rev. E to Rev. F

Added Figure 23, Renumbered Sequentially .....	8
Updated Outline Dimensions .....	13

### 5/06—Rev. D to Rev. E

Changes to Figure 1 .....	1
Change to Specifications Table 1 .....	3
Changes to Specifications Table 2.....	4
Changes to Table 3.....	5
Changes to Figure 23 and Figure 24.....	9
Changes to Figure 32.....	12
Updated the Ordering Guide .....	14

### 4/06—Rev. C to Rev. D

Change to Pin Configuration Caption.....	1
Changes to Features.....	1
Change to Table 2 .....	4
Change to Figure 2 .....	4
Changes to Figure 10 and Figure 11 .....	6

Applications Information .....	9
Gain Linearity.....	9
Thermocouple Amplifier with Cold-Junction Compensation.....	9
Precision High Gain Differential Amplifier .....	10
Isolating Large Capacitive Loads.....	10
Bilateral Current Source .....	10
Precision Absolute Value Amplifier.....	10
Precision Positive Peak Detector.....	12
Precision Threshold Detector/Amplifier .....	12
Outline Dimensions.....	13
Ordering Guide .....	14

Changes to Figure 12 through Figure 17 .....	7
Changes to Figure 18 through Figure 22 .....	8
Change to Figure 27 .....	10
Changes to Figure 30 and Figure 31.....	11
Updated Outline Dimensions .....	13
Changes to Ordering Guide .....	13

### 1/05—Rev. B to Rev. C

Edits to Features.....	1
Edits to General Description .....	1
Edits to Pin Connections.....	1
Edits to Electrical Characteristics .....	2, 3
Global deletion of references to OP177E .....	3, 4, 10
Edits to Absolute Maximum Ratings .....	5
Edits to Package Type .....	5
Edits to Ordering Guide .....	5
Edit to Outline Dimensions .....	11

### 11/95—Rev. 0: Initial Version

## SPECIFICATIONS

### ELECTRICAL CHARACTERISTICS

@  $V_S = \pm 15$  V,  $T_A = 25^\circ\text{C}$ , unless otherwise noted.

**Table 1.**

Parameter	Symbol	Conditions	OP177F			OP177G			Unit
			Min	Typ	Max	Min	Typ	Max	
INPUT OFFSET VOLTAGE	$V_{os}$			10	25		20	60	$\mu\text{V}$
LONG-TERM INPUT OFFSET <sup>1</sup>									
Voltage Stability	$\Delta V_{os}/\text{time}$			0.3			0.4		$\mu\text{V}/\text{mo}$
INPUT OFFSET CURRENT	$I_{os}$			0.3	1.5		0.3	2.8	$\text{nA}$
INPUT BIAS CURRENT	$I_B$		-0.2	+1.2	+2	-0.2	+1.2	+2.8	$\text{nA}$
INPUT NOISE VOLTAGE	$e_n$	$f_0 = 1 \text{ Hz to } 100 \text{ Hz}^2$		118	150		118	150	$\text{nV rms}$
INPUT NOISE CURRENT	$i_n$	$f_0 = 1 \text{ Hz to } 100 \text{ Hz}^2$		3	8		3	8	$\text{pA rms}$
INPUT RESISTANCE									
Differential Mode <sup>3</sup>	$R_{IN}$		26	45		18.5	45		$\text{M}\Omega$
INPUT RESISTANCE COMMON MODE	$R_{INCM}$			200			200		$\text{G}\Omega$
INPUT VOLTAGE RANGE <sup>4</sup>	$IVR$		$\pm 13$	$\pm 14$		$\pm 13$	$\pm 14$		$\text{V}$
COMMON-MODE REJECTION RATIO	$CMRR$	$V_{CM} = \pm 13 \text{ V}$	130	140		115	140		$\text{dB}$
POWER SUPPLY REJECTION RATIO	$PSRR$	$V_S = \pm 3 \text{ V to } \pm 18 \text{ V}$	115	125		110	120		$\text{dB}$
LARGE SIGNAL VOLTAGE GAIN	$A_{vo}$	$R_L \geq 2 \text{ k}\Omega, V_O = \pm 10 \text{ V}^5$	5000	12,000		2000	6000		$\text{V/mV}$
OUTPUT VOLTAGE SWING	$V_o$	$R_L \geq 10 \text{ k}\Omega$	$\pm 13.5$	$\pm 14.0$		$\pm 13.5$	$\pm 14.0$		$\text{V}$
		$R_L \geq 2 \text{ k}\Omega$	$\pm 12.5$	$\pm 13.0$		$\pm 12.5$	$\pm 13.0$		$\text{V}$
		$R_L \geq 1 \text{ k}\Omega$	$\pm 12.0$	$\pm 12.5$		$\pm 12.0$	$\pm 12.5$		$\text{V}$
SLEW RATE <sup>2</sup>	$SR$	$R_L \geq 2 \text{ k}\Omega$	0.1	0.3		0.1	0.3		$\text{V}/\mu\text{s}$
CLOSED-LOOP BANDWIDTH <sup>2</sup>	$BW$	$A_{VCL} = 1$	0.4	0.6		0.4	0.6		$\text{MHz}$
OPEN-LOOP OUTPUT RESISTANCE	$R_o$			60			60		$\Omega$
POWER CONSUMPTION	$P_D$	$V_S = \pm 15 \text{ V, no load}$	50	60		50	60		$\text{mW}$
		$V_S = \pm 3 \text{ V, no load}$	3.5	4.5		3.5	4.5		$\text{mW}$
SUPPLY CURRENT	$I_{SY}$	$V_S = \pm 15 \text{ V, no load}$	1.6	2		1.6	2		$\text{mA}$
OFFSET ADJUSTMENT RANGE		$R_P = 20 \text{ k}\Omega$		$\pm 3$			$\pm 3$		$\text{mV}$

<sup>1</sup> Long-term input offset voltage stability refers to the averaged trend line of  $V_{os}$  vs. time over extended periods after the first 30 days of operation. Excluding the initial hour of operation, changes in  $V_{os}$  during the first 30 operating days are typically less than 2.0  $\mu\text{V}$ .

<sup>2</sup> Sample tested.

<sup>3</sup> Guaranteed by design.

<sup>4</sup> Guaranteed by CMRR test condition.

<sup>5</sup> To ensure high open-loop gain throughout the  $\pm 10 \text{ V}$  output range,  $A_{vo}$  is tested at  $-10 \text{ V} \leq V_o \leq 0 \text{ V}, 0 \text{ V} \leq V_o \leq +10 \text{ V}$ , and  $-10 \text{ V} \leq V_o \leq +10 \text{ V}$ .

# OP177

@  $V_S = \pm 15$  V,  $-40^\circ\text{C} \leq T_A \leq +85^\circ\text{C}$ , unless otherwise noted.

**Table 2.**

Parameter	Symbol	Conditions	OP177F	OP177G	Unit
			Min	Typ	Max
INPUT					
Input Offset Voltage	$V_{OS}$		15	40	20 100 $\mu\text{V}$
Average Input Offset Voltage Drift <sup>1</sup>	$TCV_{OS}$		0.1	0.3	0.7 1.2 $\mu\text{V}/^\circ\text{C}$
Input Offset Current	$I_{OS}$		0.5	2.2	0.5 4.5 nA
Average Input Offset Current Drift <sup>2</sup>	$TCI_{OS}$		1.5	40	1.5 85 pA/ $^\circ\text{C}$
Input Bias Current	$I_B$		-0.2	+2.4	+4 +2.4 $\pm 6$ nA
Average Input Bias Current Drift <sup>2</sup>	$TCI_B$		8	40	15 60 pA/ $^\circ\text{C}$
Input Voltage Range <sup>3</sup>	$IVR$		$\pm 13$	$\pm 13.5$	$\pm 13$ $\pm 13.5$ V
COMMON-MODE REJECTION RATIO	CMRR	$V_{CM} = \pm 13$ V	120	140	dB
POWER SUPPLY REJECTION RATIO	PSRR	$V_S = \pm 3$ V to $\pm 18$ V	110	120	dB
LARGE-SIGNAL VOLTAGE GAIN <sup>4</sup>	$A_{VO}$	$R_L \geq 2$ k $\Omega$ , $V_O = \pm 10$ V	2000	6000	V/mV
OUTPUT VOLTAGE SWING	$V_O$	$R_L \geq 2$ k $\Omega$	$\pm 12$	$\pm 13$	V
POWER CONSUMPTION	$P_D$	$V_S = \pm 15$ V, no load	60	75	mW
SUPPLY CURRENT	$I_{SV}$	$V_S = \pm 15$ V, no load	20	2.5	mA

<sup>1</sup>  $TCV_{OS}$  is sample tested.

<sup>2</sup> Guaranteed by endpoint limits.

<sup>3</sup> Guaranteed by CMRR test condition.

<sup>4</sup> To ensure high open-loop gain throughout the  $\pm 10$  V output range,  $A_{VO}$  is tested at  $-10$  V  $\leq V_O \leq 0$  V,  $0$  V  $\leq V_O \leq +10$  V, and  $-10$  V  $\leq V_O \leq +10$  V.

## TEST CIRCUITS

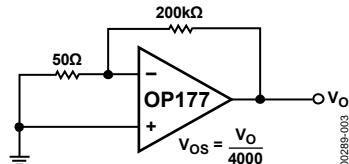


Figure 3. Typical Offset Voltage Test Circuit

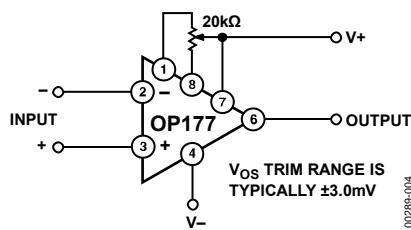


Figure 4. Optional Offset Nulling Circuit

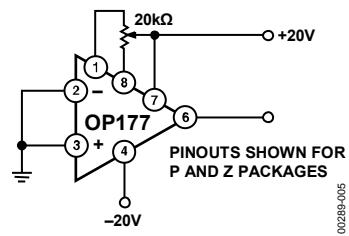


Figure 5. Burn-In Circuit

## ABSOLUTE MAXIMUM RATINGS

Table 3.

Parameter	Ratings
Supply Voltage	$\pm 22\text{ V}$
Internal Power Dissipation <sup>1</sup>	500 mW
Differential Input Voltage	$\pm 30\text{ V}$
Input Voltage	$\pm 22\text{ V}$
Output Short-Circuit Duration	Indefinite
Storage Temperature Range	$-65^\circ\text{C}$ to $+125^\circ\text{C}$
Operating Temperature Range	$-40^\circ\text{C}$ to $+85^\circ\text{C}$
Lead Temperature (Soldering, 60 sec)	300°C
DICE Junction Temperature ( $T_j$ )	$-65^\circ\text{C}$ to $+150^\circ\text{C}$

<sup>1</sup> For supply voltages less than  $\pm 22\text{ V}$ , the absolute maximum input voltage is equal to the supply voltage.

Stresses above those listed under Absolute Maximum Ratings may cause permanent damage to the device. This is a stress rating only; functional operation of the device at these or any other conditions above those indicated in the operational section of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

## THERMAL RESISTANCE

$\theta_{JA}$  is specified for worst-case mounting conditions, that is,  $\theta_{JA}$  is specified for device in socket for PDIP;  $\theta_{JA}$  is specified for device soldered to printed circuit board for SOIC package.

Table 4. Thermal Resistance

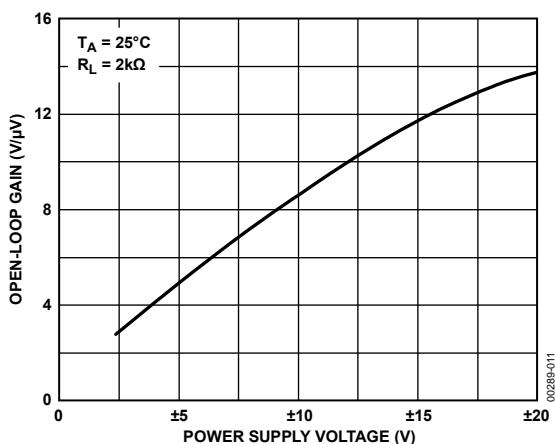
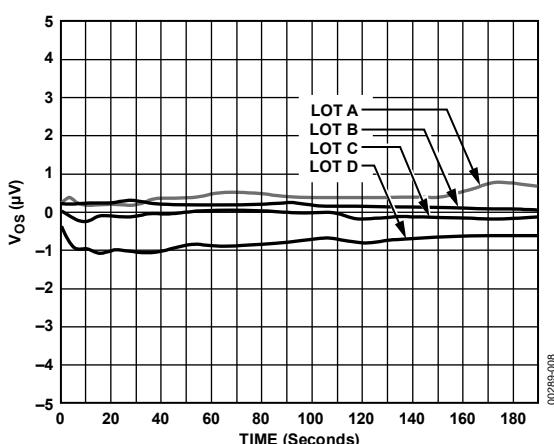
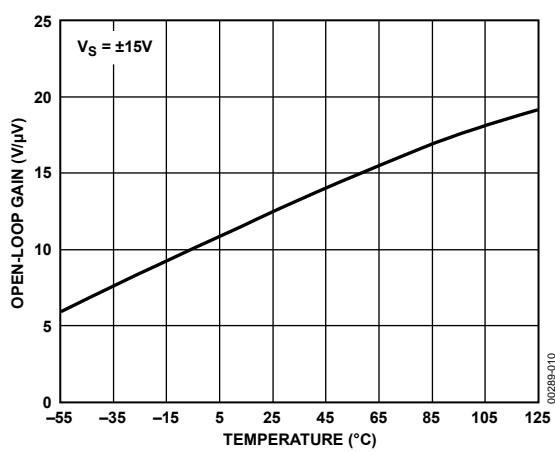
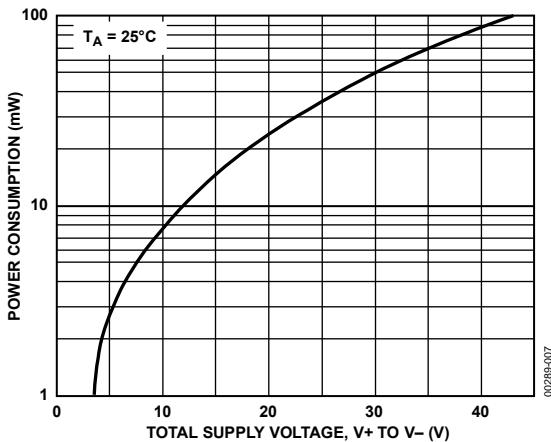
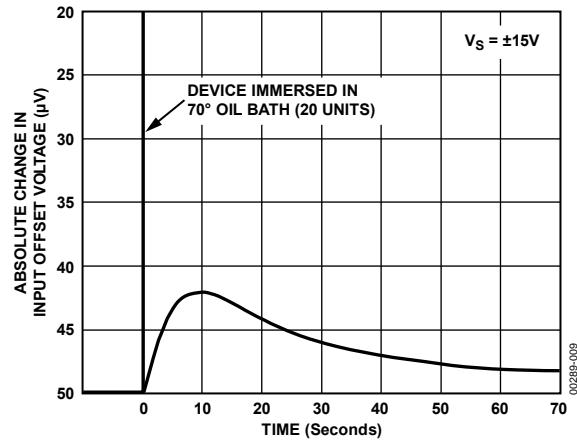
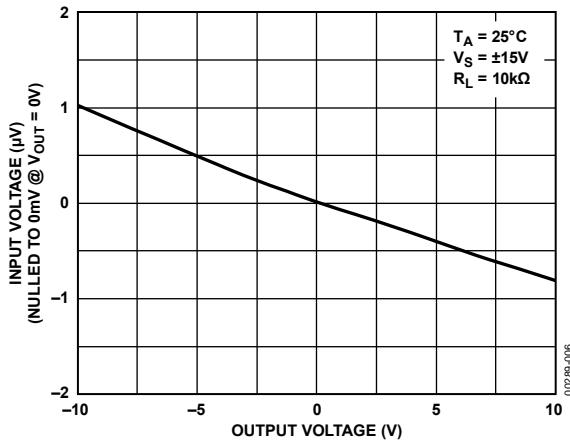
Package Type	$\theta_{JA}$	$\theta_{JC}$	Unit
8-Lead PDIP (P-Suffix)	103	43	°C/W
8-Lead SOIC (S-Suffix)	158	43	°C/W

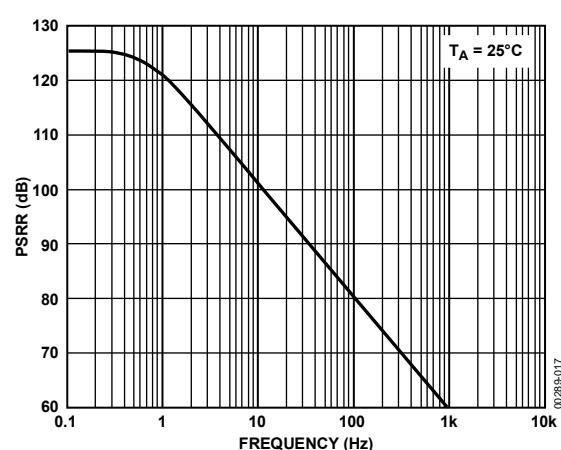
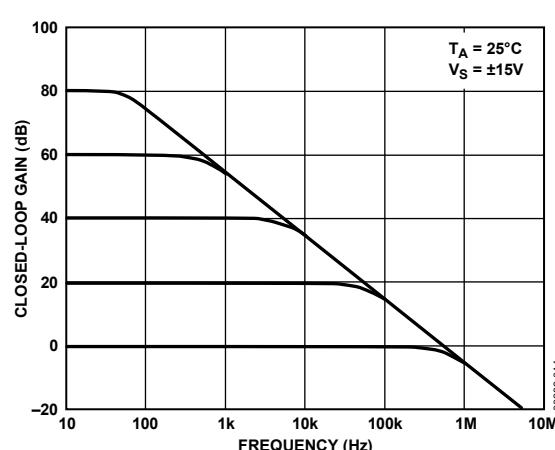
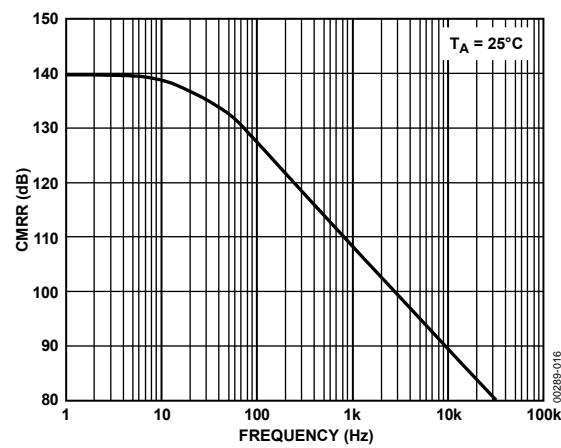
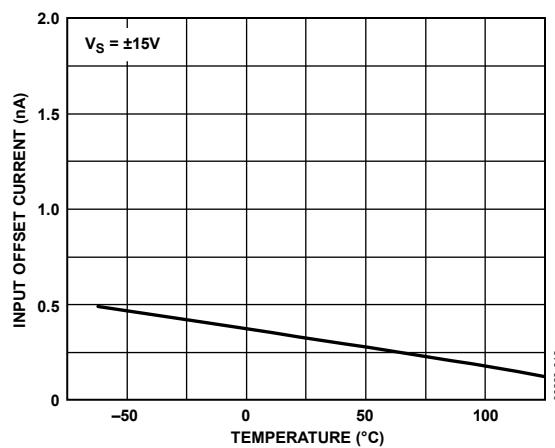
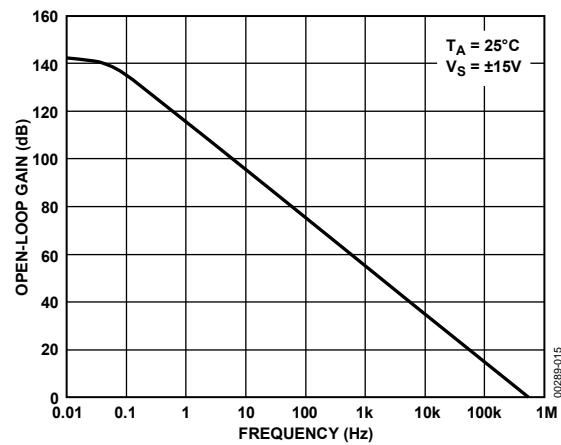
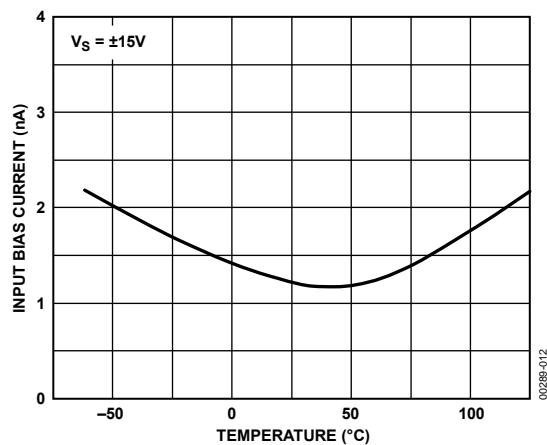
## ESD CAUTION

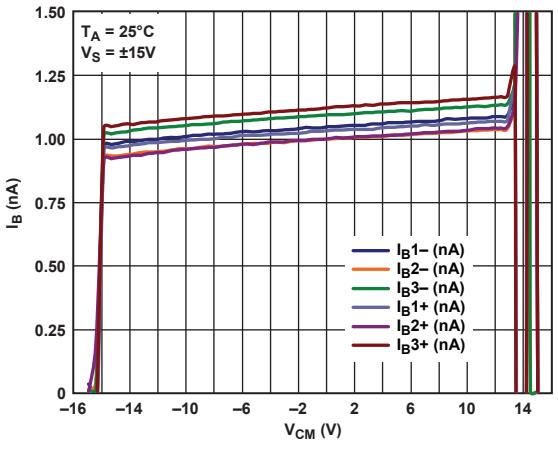
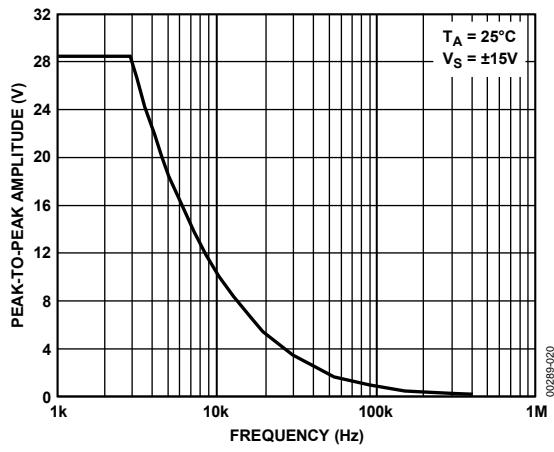
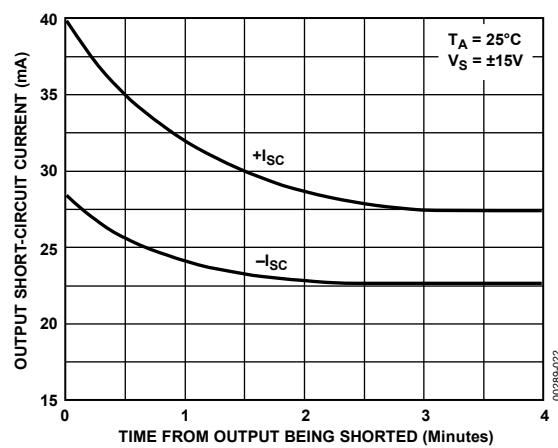
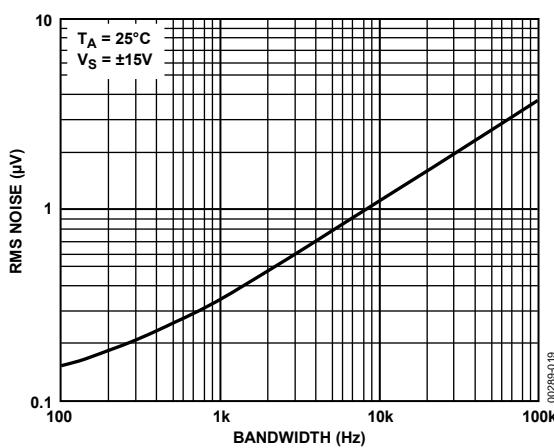
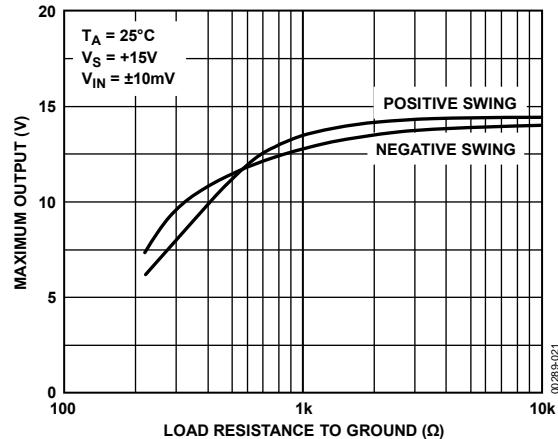
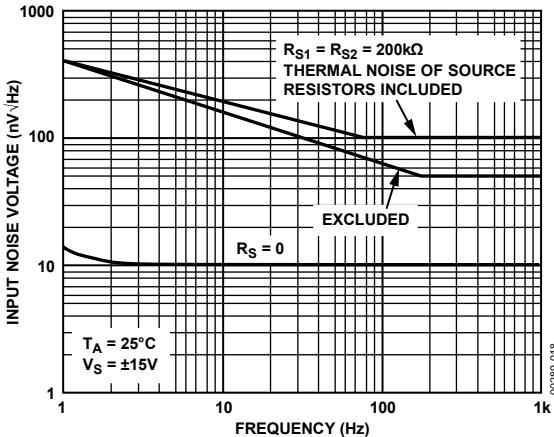
ESD (electrostatic discharge) sensitive device. Electrostatic charges as high as 4000V readily accumulate on the human body and test equipment and can discharge without detection. Although this product features proprietary ESD protection circuitry, permanent damage may occur on devices subjected to high energy electrostatic discharges. Therefore, proper ESD precautions are recommended to avoid performance degradation or loss of functionality.



## TYPICAL PERFORMANCE CHARACTERISTICS







## APPLICATIONS INFORMATION

### GAIN LINEARITY

The actual open-loop gain of most monolithic op amps varies at different output voltages. This nonlinearity causes errors in high closed-loop gain circuits.

It is important to know that the manufacturer's Avo specification is only a part of the solution because all automated testers use endpoint testing and, therefore, show only the average gain. For example, Figure 24 shows a typical precision op amp with a respectable open-loop gain of 650 V/mV. However, the gain is not constant through the output voltage range, causing nonlinear errors. An ideal op amp shows a horizontal scope trace.

Figure 25 shows the OP177 output gain linearity trace with its truly impressive average Avo of 12,000 V/mV. The output trace is virtually horizontal at all points, assuring extremely high gain accuracy. Analog Devices also performs additional testing to ensure consistent high open-loop gain at various output voltages. Figure 26 is a simple open-loop gain test circuit.

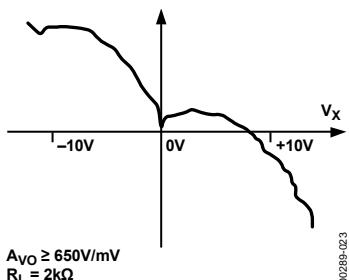


Figure 24. Typical Precision Op Amp

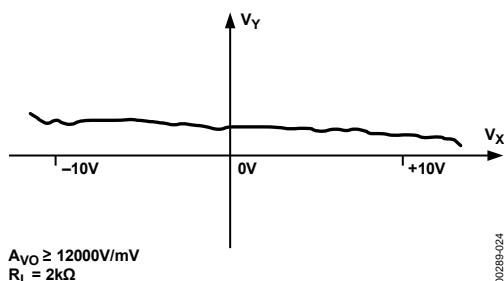


Figure 25. Output Gain Linearity Trace

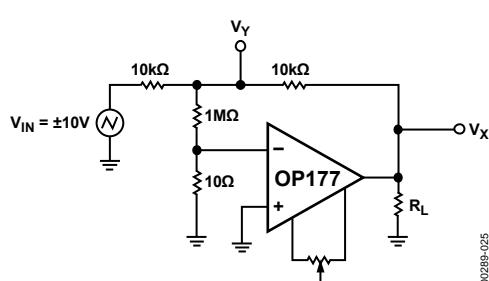


Figure 26. Open-Loop Gain Linearity Test Circuit

### THERMOCOUPLE AMPLIFIER WITH COLD-JUNCTION COMPENSATION

An example of a precision circuit is a thermocouple amplifier that must accurately amplify very low level signals without introducing linearity and offset errors to the circuit. In this circuit, an S-type thermocouple with a Seebeck coefficient of  $10.3 \mu\text{V}/^\circ\text{C}$  produces  $10.3 \text{ mV}$  of output voltage at a temperature of  $1000^\circ\text{C}$ . The amplifier gain is set at 973.16, thus, it produces an output voltage of  $10.024 \text{ V}$ . Extended temperature ranges beyond  $1500^\circ\text{C}$  are accomplished by reducing the amplifier gain. The circuit uses a low cost diode to sense the temperature at the terminating junctions and, in turn, compensates for any ambient temperature change. The OP177, with its high open-loop gain plus low offset voltage and drift, combines to yield a precise temperature sensing circuit. Circuit values for other thermocouple types are listed in Table 5.

Table 5.

Thermocouple Type	Seebeck Coefficient	R1	R2	R7	R9
K	$39.2 \mu\text{V}/^\circ\text{C}$	$110 \Omega$	$5.76 \text{ k}\Omega$	$102 \text{ k}\Omega$	$269 \text{ k}\Omega$
J	$50.2 \mu\text{V}/^\circ\text{C}$	$100 \Omega$	$4.02 \text{ k}\Omega$	$80.6 \text{ k}\Omega$	$200 \text{ k}\Omega$
S	$10.3 \mu\text{V}/^\circ\text{C}$	$100 \Omega$	$20.5 \text{ k}\Omega$	$392 \text{ k}\Omega$	$1.07 \text{ M}\Omega$

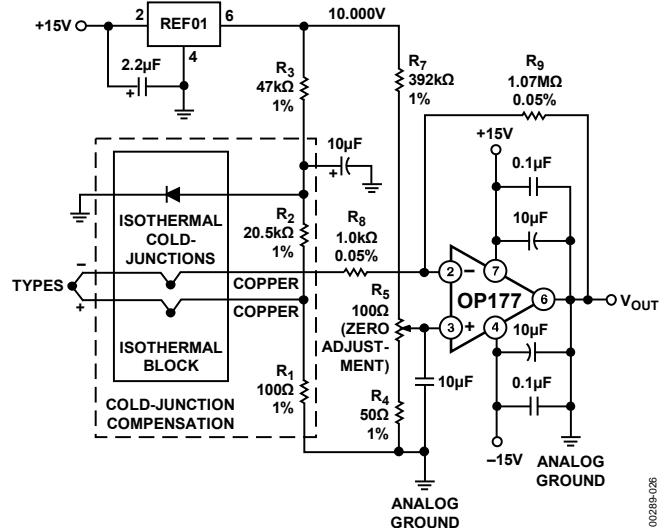


Figure 27. Thermocouple Amplifier with Cold Junction Compensation

## PRECISION HIGH GAIN DIFFERENTIAL AMPLIFIER

The high gain, gain linearity, CMRR, and low TCV<sub>os</sub> of the OP177 make it possible to obtain performance not previously available in single stage, very high gain amplifier applications. See Figure 28.

For best CMR,  $\frac{R1}{R2}$  must equal  $\frac{R3}{R4}$

In this example, with a 10 mV differential signal, the maximum errors are listed in Table 6.

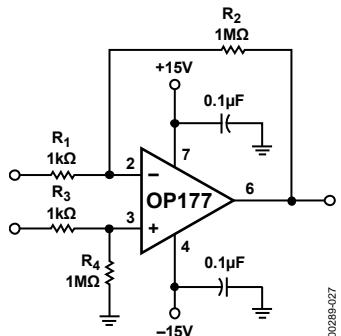


Figure 28. Precision High Gain Differential Amplifier

Table 6. High Gain Differential Amp Performance

Type	Amount
Common-Mode Voltage	0.1%/V
Gain Linearity, Worst Case	0.02%
TCV <sub>os</sub>	0.0003%/°C
TCIos	0.008%/°C

## ISOLATING LARGE CAPACITIVE LOADS

The circuit shown in Figure 29 reduces maximum slew rate but allows driving capacitive loads of any size without instability. Because the 100 Ω resistor is inside the feedback loop, its effect on output impedance is reduced to insignificance by the high open loop gain of the OP177.

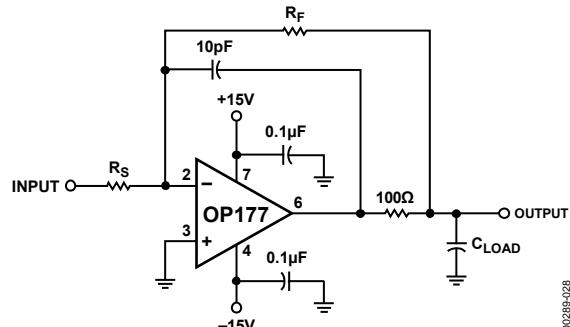


Figure 29. Isolating Capacitive Loads

## BILATERAL CURRENT SOURCE

The current sources shown in Figure 30 supply both positive and negative currents into a grounded load.

Note that

$$Z_o = \frac{R5 \left( \frac{R4}{R2} + 1 \right)}{\frac{R5 + R4}{R2} - \frac{R3}{R1}}$$

and that for Z<sub>o</sub> to be infinite

$$\frac{R5 + R4}{R2} \text{ must} = \frac{R3}{R1}$$

## PRECISION ABSOLUTE VALUE AMPLIFIER

The high gain and low TCV<sub>os</sub> assure accurate operation with inputs from microvolts to volts. In this circuit, the signal always appears as a common-mode signal to the op amps (for details, see Figure 31).

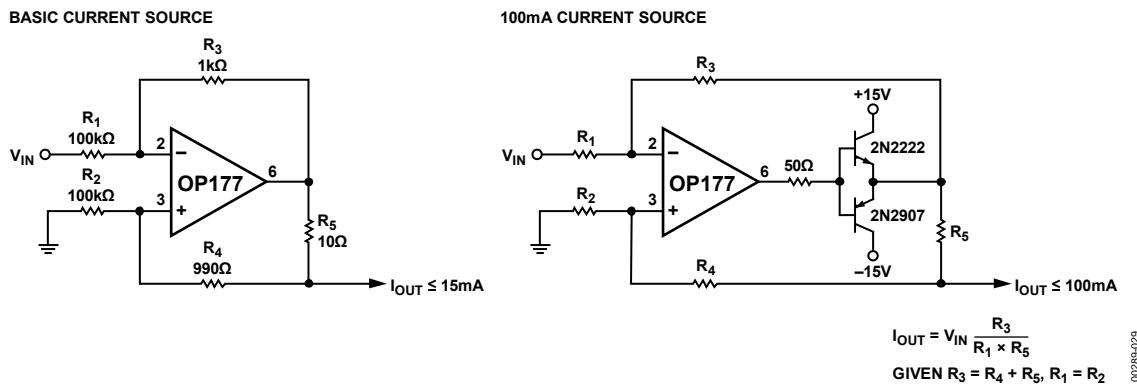


Figure 30. Bilateral Current Source

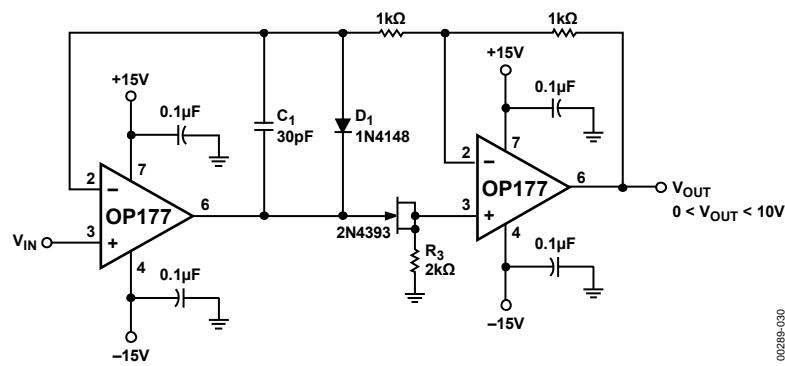


Figure 31. Precision Absolute Value Amplifier

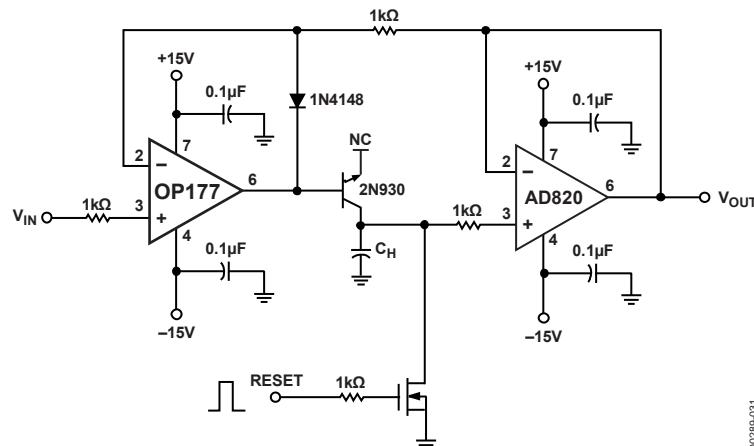


Figure 32. Precision Positive Peak Detector

## PRECISION POSITIVE PEAK DETECTOR

In Figure 32,  $C_H$  must be polystyrene, Teflon®, or polyethylene to minimize dielectric absorption and leakage. The droop rate is determined by the size of  $C_H$  and the bias current of the AD820.

## PRECISION THRESHOLD DETECTOR/AMPLIFIER

In Figure 33, when  $V_{IN} < V_{TH}$ , amplifier output swings negative, reverse biasing diode D<sub>1</sub>.  $V_{OUT} = V_{TH}$  if  $R_L = \infty$ . When  $V_{IN} \geq V_{TH}$ , the loop closes.

$$V_{OUT} = V_{TH} + (V_{IN} - V_{TH}) \left( 1 + \frac{R_F}{R_S} \right)$$

$C_C$  is selected to smooth the response of the loop.

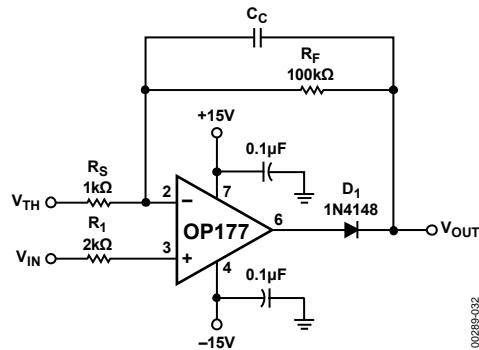
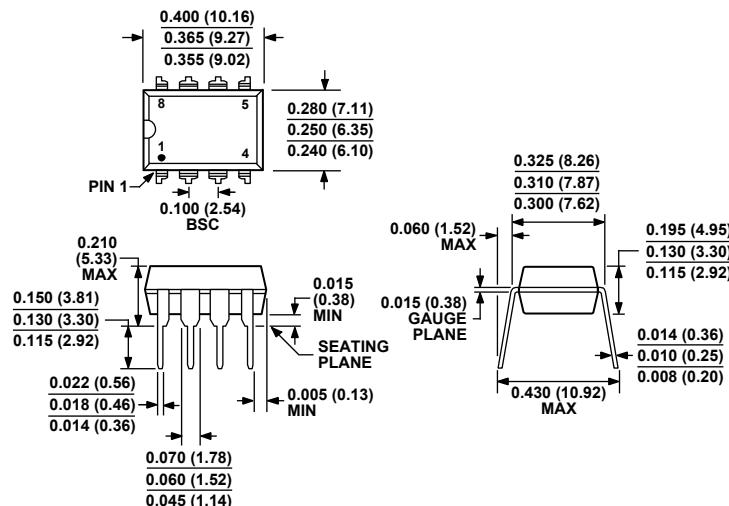


Figure 33. Precision Threshold Detector/Amplifier

00289-032

## OUTLINE DIMENSIONS



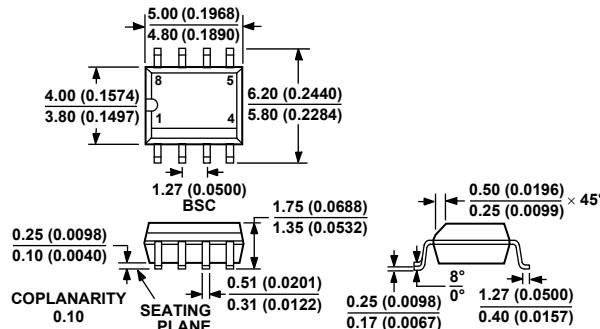
COMPLIANT TO JEDEC STANDARDS MS-001-BA  
 CONTROLLING DIMENSIONS ARE IN INCHES; MILLIMETER DIMENSIONS  
 (IN PARENTHESES) ARE ROUNDED-OFF INCH EQUIVALENTS FOR  
 REFERENCE ONLY AND ARE NOT APPROPRIATE FOR USE IN DESIGN.  
 CORNER LEADS MAY BE CONFIGURED AS WHOLE OR HALF LEADS.

Figure 34. 8-Lead Plastic Dual In-Line Package (PDIP)

P-Suffix

(N-8)

Dimensions show in inches and (millimeters)



COMPLIANT TO JEDEC STANDARDS MS-012-AA  
 CONTROLLING DIMENSIONS ARE IN MILLIMETERS; INCH DIMENSIONS  
 (IN PARENTHESES) ARE ROUNDED-OFF MILLIMETER EQUIVALENTS FOR  
 REFERENCE ONLY AND ARE NOT APPROPRIATE FOR USE IN DESIGN.

Figure 35. 8-Lead Standard Small Outline Package (SOIC\_N)

S-Suffix

(R-8)

Dimensions shown in millimeters and (inches)

**ORDERING GUIDE**

<b>Model</b>	<b>Temperature Range</b>	<b>Package Description</b>	<b>Package Option</b>
OP177FP	–40°C to +85°C	8-Lead PDIP	P-Suffix (N-8)
OP177FPZ <sup>1</sup>	–40°C to +85°C	8-Lead PDIP	P-Suffix (N-8)
OP177GP	–40°C to +85°C	8-Lead PDIP	P-Suffix (N-8)
OP177GPZ <sup>1</sup>	–40°C to +85°C	8-Lead PDIP	P-Suffix (N-8)
OP177FS	–40°C to +85°C	8-Lead SOIC_N	S-Suffix (R-8)
OP177FS-REEL	–40°C to +85°C	8-Lead SOIC_N	S-Suffix (R-8)
OP177FS-REEL7	–40°C to +85°C	8-Lead SOIC_N	S-Suffix (R-8)
OP177FSZ <sup>1</sup>	–40°C to +85°C	8-Lead SOIC_N	S-Suffix (R-8)
OP177FSZ-REEL <sup>1</sup>	–40°C to +85°C	8-Lead SOIC_N	S-Suffix (R-8)
OP177FSZ-REEL7 <sup>1</sup>	–40°C to +85°C	8-Lead SOIC_N	S-Suffix (R-8)
OP177GS	–40°C to +85°C	8-Lead SOIC_N	S-Suffix (R-8)
OP177GS-REEL	–40°C to +85°C	8-Lead SOIC_N	S-Suffix (R-8)
OP177GS-REEL7	–40°C to +85°C	8-Lead SOIC_N	S-Suffix (R-8)
OP177GSZ <sup>1</sup>	–40°C to +85°C	8-Lead SOIC_N	S-Suffix (R-8)
OP177GSZ-REEL <sup>1</sup>	–40°C to +85°C	8-Lead SOIC_N	S-Suffix (R-8)
OP177GSZ-REEL7 <sup>1</sup>	–40°C to +85°C	8-Lead SOIC_N	S-Suffix (R-8)

<sup>1</sup> Z = RoHS Compliant Part.

**NOTES**

**OP177**

**NOTES**

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